# Topic: N15A-T011

## LightSpin Technologies, Inc.

#### Ultra scaling of SPAD arrays for high-speed laser ranging

LightSpin Technologies is developing the Photomultiplier Chip, a device that can detect optical signals with high internal gain, low noise, and multi-GHz bandwidths. Photomultiplier Chips allow precise timing of signals as small as single photons. LightSpin's approach enables unique optimizations including speed, sensitivity, and radiation hardness for applications including free space optical communications, remote sensing, medical imaging, high energy physics, and the detection of special nuclear materials. LightSpin is the first company to demonstrate functional GaAs and GaInP devices, with preliminary experimental results indicating the potential to achieve multi-GHz bandwidths. LightSpin's Photomultiplier Chip technology is protected with several issued and pending patents on the design and fabrication techniques. LightSpin intends to provide commercial detector modules to prime contractors for Department of Defense applications.

## Technology Category Alignment:

EO/IR Components for sensing, transmission and communication Manufacturing Technology for Affordability Electro-Optical/Infrared (EO/IR) Guidance, Navigation & Control (GN&C) and Data Links

Contact: Eric Harmon, Ph.D. harmon@lightspintech.com (508) 930-4198 http://www.lightspintech.com/home.html SYSCOM: NAVSEA Contract: N00253-17-C-0003 Corporate Brochure: https://navystp.com/vtm/open\_file?type=brochure&id=N00253-17-C-0003



#### Department of the Navy SBIR/STTR Transition Program

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#### NAVSEA #2018-0517

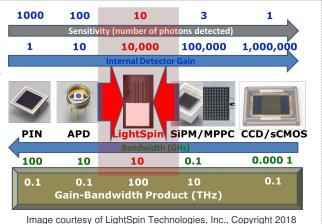
### WHO

SYSCOM: NAVSEA

- Sponsoring Program: PEO IWS 2.0 Above Water Sensors
- Transition Target: Working to identify potential Transition Targets
- **TPOC:** (812)854-4694

Other transition opportunities: Free Space Optical Communications Laser Ranging and Tracking Quantum Key Distribution

Notes: Current photon detector technologies have either low sensitivity/ligh bandwidth or high sensitivity/low bandwidth. This can be characterized by a gain-bandwidth product. Most photodetector technologies exhibit a gain bandwidth product of about 0.1 THz, with single photons only being detectable



# WHAT

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**Operational Need and Improvement:** Solid-state photon detectors for ship-to-ship free space optical communications and precision localization, improving the ability of multiple ships to act in concert and combine shipboard sensor data. Visible wavelengths were chosen because low-cost lasers are readily available and these wavelengths do not interfere with shipboard sensors (LADAR and tracking systems). Currently available photodetectors are either high-speed/low-sensitivity or low-speed/high-sensitivity. There is a strong need for detecting single-photons and multiple-photon signals with bandwidths exceeding 1 GHz.

Specifications Required: Single Photon Sensitivity Visible Wavelengths (400 - 650 nm) 1 GHz @ 1.0 mm<sup>2</sup> area (CW bandwidth)

Ultra scaling of SPAD arrays for high-speed laser ranging

- 4 GHz @ 0.5 mm<sup>2</sup> area (CW bandwidth)
- 10 GHz @ 0.5 mm^2 area (pulsed bandwidth)

**Technology Developed:** Compound semiconductor Single Photon Avalanche Diode (SPAD) arrays Similar to Silicon Photomultipliers (SiPMs), which are silicon SPAD array devices. Analogous to Microchannel Plate (MCP) vacuum tube photodetectors, where the photocathode and array of channels is replaced by an array of SPAD devices.

**Warfighter Value:** LightSpin's Photomultiplier Chip provides a unique capability to fill the gaps in competing technologies, increasing the bandwidth for free space optical communications by at least an order of magnitude, and improving the range and precision of targeting/tracking applications.

(1) Higher bandwidth. Due to LIghtSpin's proprietary process and the use of high performance compound semiconductors, LightSpin is developing Photomultiplier Chips to achieve single photon detection with bandwidths in excess of 1 GHz, about an order of magnitude larger than currently available SiPMs

(2) Wavelength customizable: LightSpin's technology can be targeted to specific applications:. GaInP for highest sensitivity in visible wavelengths, with low noise and improved radiation hardness. Silicon for lowest cost, while maintaining GHz bandwidths and high sensitivity. InGaAs for operation at wavelengths between 900 nm and 2500 nm.

# HOW

**Projected Business Model:** LightSpin Technologies, Inc. (LTI) was founded in 2001 to develop and commercialize high performance compound semiconductor components. Through a systematic development approach, LTI has demonstrated superior III-V photodetector technology. LTI has an excellent track record with the SBIR program and other R&D initiatives working across multiple government agencies. For this specific SBIR effort LTI anticipates outsourcing fabrication to commercial foundries but retain testing and validation In-House. LTI plans to sell the finished Photodetector Module to various Primes.

**Company Objectives:** LTI is developing a new, ultimate sensitivity photodetector technology called the Photomultiplier Chip. Photomultiplier chips detect optical signals with high internal gain, low noise, and multi-GHz bandwidths, allowing precise timing of signals as small as single photons. This technology enables improved remote sensing and free space optical communications, improved radiation hardness for high energy physics applications, higher sensitivity imaging for medical imaging applications, and improved detection of illicit radioactive material.

**Potential Commercial Applications:** DoD: Free Space Communications, tracking, and positioning Healthcare: Critical component for high performance positron emission tomography (PET) imaging Automobile: autonomous navigation sensors

#### **WHEN**

at GHz bandwidth!

# **Contract Number:** N00253-17-C-0003 **Ending on:** May 18, 2019

| Milestone                          | Risk<br>Level | Measure of Success          | Ending<br>TRL | Date              |
|------------------------------------|---------------|-----------------------------|---------------|-------------------|
| 5 micron pitch SPAD arrays         | Low           | Laboratory<br>Demonstration | TRL-4         | September<br>2018 |
| 0.5 GHz CW Bandwidth               | Low           | Laboratory<br>Demonstration | TRL-4         | September<br>2018 |
| 2.0 GHz pulsed Bandwidth           | Med           | Laboratory<br>Demonstration | TRL-3         | January 2019      |
| 1.0 GHz CW Bandwidth, 30 dB<br>DNR | Med           | Laboratory<br>Demonstration | TRL-5         | May 2019          |
| 4.0 GHz pulsed Bandwidth, 5 dB DNR | High          | Laboratory<br>Demonstration | TRL-3         | May 2019          |
| Prototype Quadrant detector        | Med           | Laboratory<br>Demonstration | TRL-5         | May 2019          |

when the bandwidth is below 1 MHz. Newly developed SPAD array devices (LightSpin and SiPM) achieve

single photon sensitivity with high gain-bandwidth product. laying a foundation for detecting single photons